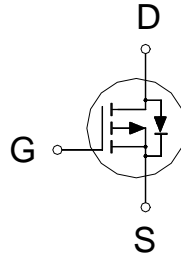


P-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

$BV_{DSS}$	-60V
$R_{DS(on) (MAX.)}$	150m $\Omega$
$I_D$	-2.2A



Pb-Free Lead Plating & Halogen Free



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNIT
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_A = 25\text{ }^\circ\text{C}$	$I_D$	-2.2	A
	$T_A = 70\text{ }^\circ\text{C}$		-1.4	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	-8.8	
Power Dissipation	$T_A = 25\text{ }^\circ\text{C}$	$P_D$	1.25	W
	$T_A = 70\text{ }^\circ\text{C}$		0.8	
Operating Junction & Storage Temperature Range		$T_{j}, T_{stg}$	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Ambient	$R_{\theta JA}$		100	$^\circ\text{C} / \text{W}$

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$



ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)

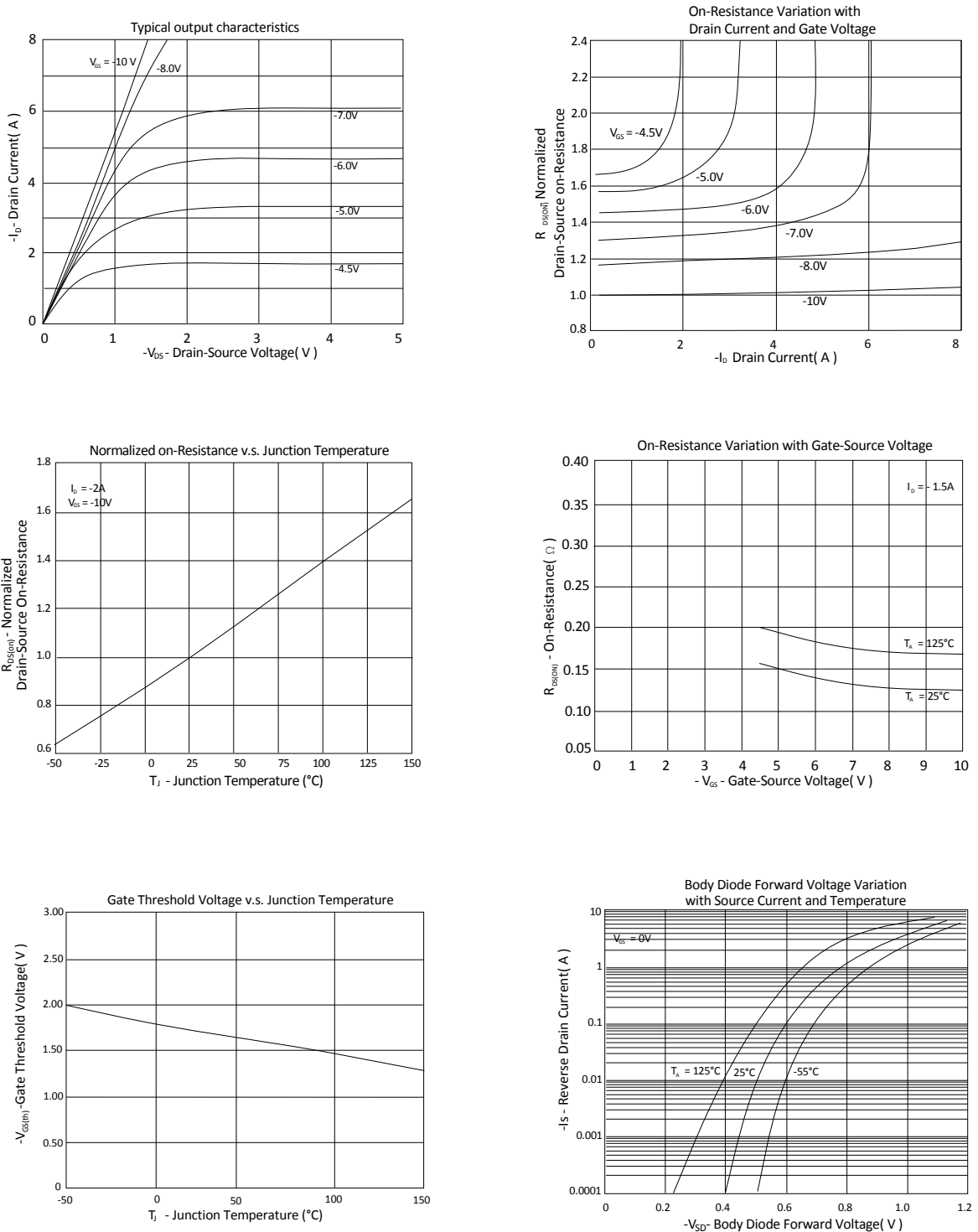
PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.7	-3	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -48V, V_{GS} = 0V$			-1	$\mu A$
		$V_{DS} = -40V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$			-25	
On-State Drain Current <sup>1</sup>	$I_{D(ON)}$	$V_{DS} = -5V, V_{GS} = -10V$	-2.2			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(ON)}$	$V_{GS} = -10V, I_D = -2A$		125	150	$m\Omega$
		$V_{GS} = -4.5V, I_D = -1.5A$		160	200	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = -5V, I_D = -2A$		3		S
<b>DYNAMIC</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = -30V, f = 1MHz$		1032		$pF$
Output Capacitance	$C_{oss}$			66		
Reverse Transfer Capacitance	$C_{rss}$			48		
Total Gate Charge <sup>1,2</sup>	$Q_g$	$V_{DS} = -10V, V_{GS} = -10V,$ $I_D = -2A$		12.3		nC
Gate-Source Charge <sup>1,2</sup>	$Q_{gs}$			1.6		
Gate-Drain Charge <sup>1,2</sup>	$Q_{gd}$			2.4		
Turn-On Delay Time <sup>1,2</sup>	$t_{d(on)}$	$V_{DS} = -10V,$ $I_D = -1A, V_{GS} = -10V, R_{GS} = 6\Omega$		12		nS
Rise Time <sup>1,2</sup>	$t_r$			20		
Turn-Off Delay Time <sup>1,2</sup>	$t_{d(off)}$			20		
Fall Time <sup>1,2</sup>	$t_f$			25		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_C = 25\text{ }^\circ\text{C}</math>)</b>						
Continuous Current	$I_S$				-2	A
Pulsed Current <sup>3</sup>	$I_{SM}$				-8	
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = I_S, V_{GS} = 0V$			1.2	V

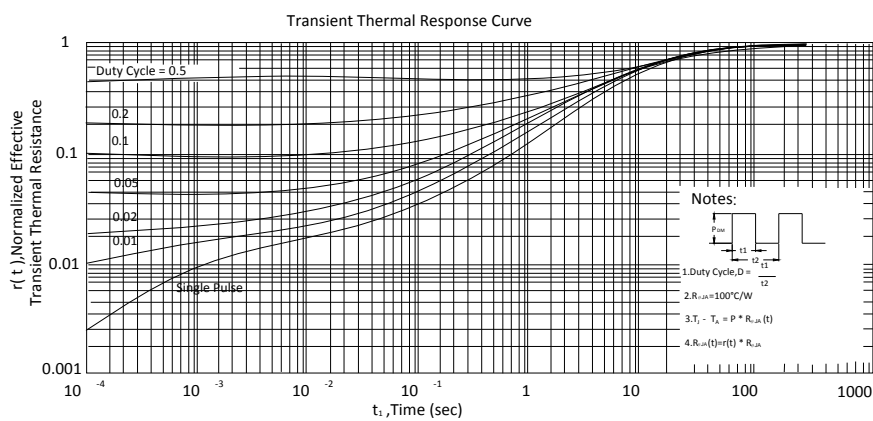
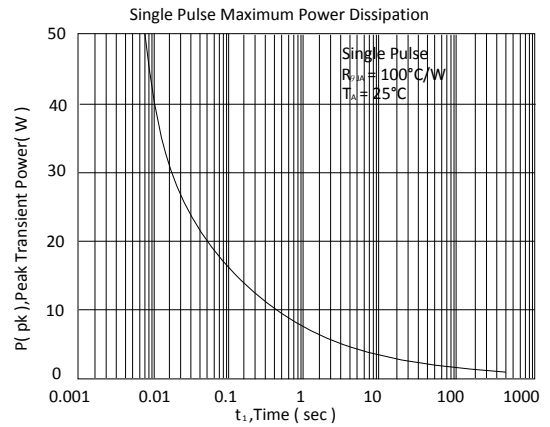
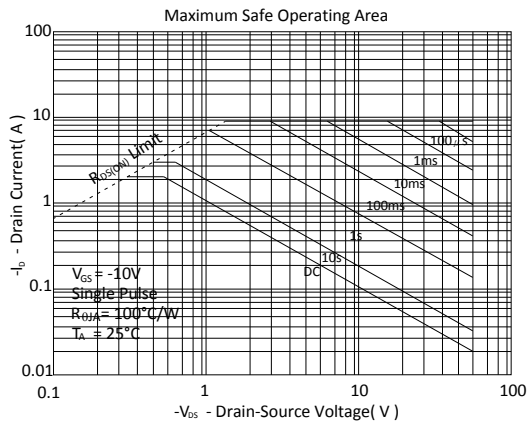
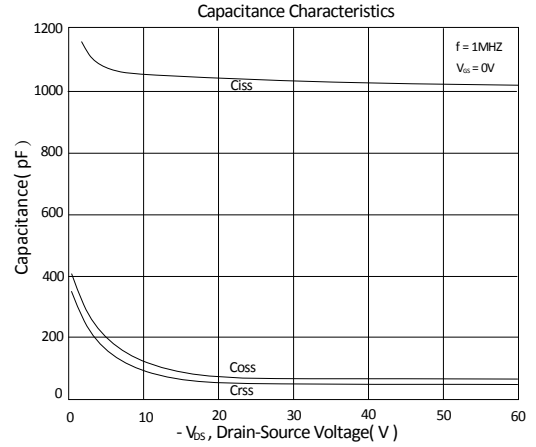
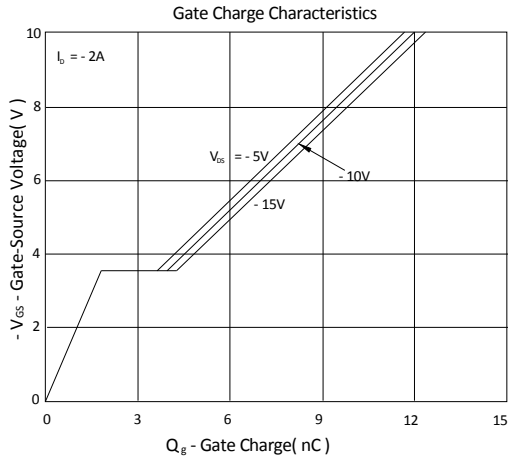
<sup>1</sup>Pulse test : Pulse Width  $\leq 300\ \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .

<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

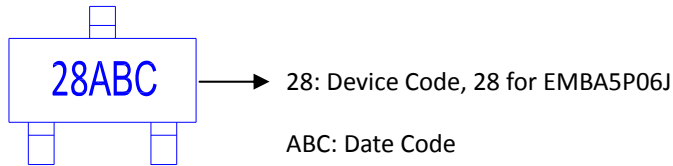
TYPICAL CHARACTERISTICS





Ordering & Marking Information:

Device Name: EMBA5P06J for SOT-23



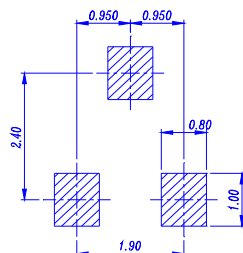
Outline Drawing



Dimension in mm

Dimension	A	A1	A2	b	C	D	E	E1	e	e1	F	G	L1
Min.	0.7	0		0.35	0.1	2.8	2.6	1.5	0.9		0.8	0.3	0.55
Typ.						2.9	2.8	1.6	0.95	1.9			
Max.	1.12	0.1		0.5	0.2	3	3	1.7	1		1.2	0.6	0.65

Footprint



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